

Ten Milliseconds for Aluminum Cavities in the Quantum Regime

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A promising quantum computing architecture couples superconducting qubits to microwave resonators (circuit QED), a system in which three-dimensional microwave cavities have become a valuable resource. Such cavities have surface-to-volume ratios, or participation ratios a thousandfold smaller than in planar devices, deemphasizing potentially lossy surface elements by an equal amount. Motivated by this principle, we have tested aluminum superconducting cavity resonators with internal quality factors greater than 0.5 billion and intrinsic lifetimes reaching 0.01 seconds at single photon power and millikelvin temperatures. These results are the first to explore the use of superconducting aluminum, a ubiquitous material in circuit QED, as the basis of highly coherent ($Q \approx 10^7$ - 10^9) cavity resonators. Measurements confirm the cavities' predicted insensitivity to quasiparticles (kinetic inductance fraction-5ppm) and an absence of two level dielectric fluctuations.

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In circuit quantum electrodynamics (cQED), microwave resonators protect superconducting qubits from decoherence, suppress spontaneous emission¹, allow for quantum non-demolition measurements^{2,3}, and serve as quantum memories⁴. Single photon lifetimes between 10-50 μ s ($Q \approx 10^6$) have been achieved in thin film resonators with careful surface preparation and geometrical optimization⁵⁻⁷. The route toward an optimal geometry also sheds light on the physical mechanisms responsible for damping. Planar resonators with larger features are generally found to be higher quality. This trend is consistent with loss dominated by surface elements⁵⁻⁸. As resonator geometries grow, the relative amount of energy stored in surface defects - their participation ratios - tend to decrease⁹. Thus, larger resonators are longer lived in the presence of surface loss.

Three dimensional, macroscopic cavity resonators are at the extreme limit of this trend and historically exhibit remarkable lifetimes¹⁰. Progress with superconducting niobium cavities for particle acceleration has led to dwell times of seconds for RF powers approaching critical-field strength at 2 K bath temperatures¹¹. At circulating powers of a single-photon, storage in excess 100 ms has been achieved in three dimensional, niobium Fabry Perot resonators at 51 GHz and 0.8 K¹², and also in 3D, niobium micromaser cavities at 22 GHz and 0.15 K¹³. The coupling of superconducting qubits to 3D microwave cavities¹⁴ suggests that the dramatic increase in photon lifetime accompanying cavity resonators may be exploitable for cQED type experiments.

We have set out to construct the first very high quality microwave cavities ($Q \gg 1M$) in superconducting aluminum while focusing on geometries that may be compatible with cQED-type experiments. We study two species of waveguide cavities (rectangular and cylindrical) supporting a diversity of modes to test the effects of material purity and surface treatment on cavity lifetimes in the quantum regime. We find that pure, chemically etched aluminum produces the best results, with rectangular resonators reaching lifetimes, $\tau_{\text{int}} = Q_{\text{int}}/\omega$ of 1.2 ms, $Q_{\text{int}} = 69M$, and cylindrical resonators as long as 10.4 ms, $Q_{\text{int}} = 740M$. Participation ratio arguments suggest another one to two orders of magnitude longer lifetimes should readily be achievable in aluminum at single-photon power. Already though, these structures are appealing candidates for maintaining quantum states in cQED experiments.

A resonator solely damped by surface dielectric layer of thickness, t , and $Q_{\text{diel}} = 1/\tan \delta$ will be limited to an internal quality factor of¹⁵

$$Q_{\text{int,E}} = \frac{Q_{\text{diel}} \int_V |E|^2 dV}{\epsilon_r \int_S |E|^2 dA \times t} = \frac{Q_{\text{diel}} V_{\text{eff}}^E}{S_{\text{eff}}^E} = \frac{Q_{\text{diel}}}{p_{\text{diel}}} \quad (1)$$

where the electric field weighted surface-to-volume ratio, $S_{\text{eff}}^E/V_{\text{eff}}^E$, is the surface dielectric participation ratio, p_{diel} ⁸. For the cavities in our study (Table I), this expression is analytically simple. The rectangular TE101 resonance has the most dielectric sensitivity, $p_{\text{diel}} = 2 \times 10^{-6}$ for an estimated AlO_x surface layer of $\epsilon_r = 10$, $t = 1$ nm. While the cylindrical TE011 mode has nominally no electric energy stored at its surfaces, we estimate from finite element simulations that a shape perturbation to the cavity introduces a $p_{\text{diel}} = 4 \times 10^{-10}$ to the mode, following the same oxide assumptions. We, therefore, expect four or

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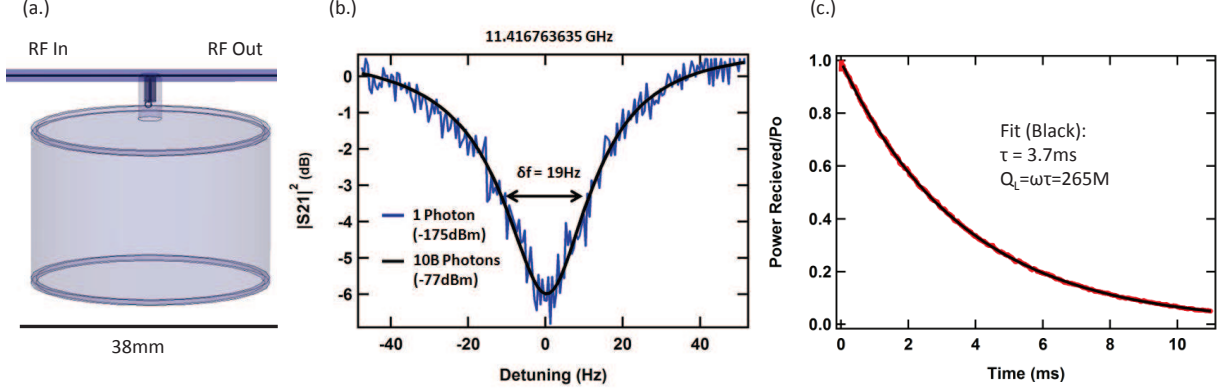


FIG. 1. (Left): Schematic of a cylindrical resonator measured in shunt configuration. (Center): Single photon (blue) and high power (black) transmission data of the configuration shown left. The best fit at single photon power is indistinguishable from the high power trace, showing the remarkable power-independence of the TE011 mode, with an internal quality factor of 600M. (Right): Phase-insensitive power decay measurements confirm no intrinsic dephasing mechanism.

ders of magnitude separation in lifetimes between these two resonators if surface dielectric loss is their only dissipation. We also note these participation ratios are infinitesimal compared to $p_{\text{diel}} \approx 10^{-3}$ estimated for planar resonators⁸. As such, surface dielectric would limit these waveguide cavities at only the $Q \approx 10^8$ - 10^{12} level if dielectric quality comparable to that of deposited resonators can be obtained with bulk aluminum.

If instead, a nonzero quasiparticle density contributes the only loss to a superconducting resonator in the form of a finite surface resistance, R_s , the resonator's quality factor will be given by¹⁵

$$Q_{\text{int,H}} = \frac{\omega \mu \lambda}{R_s} \frac{\int_V |H|^2 dV}{\int_S |H|^2 dA \times \lambda} = \frac{Q_s V_{\text{eff}}^H}{S_{\text{eff}}^H} = \frac{Q_s}{\alpha} \quad (2)$$

where the magnetic field weighted surface-to-volume ratio, $S_{\text{eff}}^H/V_{\text{eff}}^H$, is the magnetic participation ratio, α . We recognize $\omega \mu \lambda$ as the resonator's surface reactance, X_s and the ratio of X_s to R_s as the resonator's "surface Q" as introduced by the kinetic inductance detector community¹⁶. The relationship between Q , Q_s , and α indicates that the magnetic participation ratio is equivalent to the kinetic inductance fraction. Typical values for α are between 10^{-5} - 10^{-6} for the cavities studied here, many orders of magnitude lower than the (0.005-0.74) values reported for planar resonators^{16,17}. Therefore aluminum cavity resonators with at least $Q \approx 10$ B, lifetimes greater than 0.1 s in the quantum regime should be feasible from a surface resistance perspective.

Of particular interest to study is the cylindrical TE011 mode¹⁰ (Fig.1), which has nominally zero surface dielectric participation and no currents flowing across the corners of the device. The latter feature allows the cylinder to be sealed at its corners without the dissipation potentially induced at a mechanical joint. The TE011 mode is explicitly degenerate with the cylindrical TM111 mode. We lift this degeneracy with small torus shaped perturbation at the corners of the cavity, resulting in 30 MHz

detuning between the modes. Coupling to the TE011 mode is accomplished through an approach dual to the rectangular waveguide cQED set up^{14,18,19}. Here, a loop coupler excites a sub-cutoff evanescent mode in a small circular hole (3.5 mm dia) in the top of the cylindrical cavity. The coupling loop is oriented with its normal vector parallel to the cavity's $\hat{\rho}$ -direction, which establishes the correct polarity of the traveling wave to couple to the resonant TE011 mode's H_ρ field. Because our operating frequency is well below the cutoff frequency of this traveling wave, signals are exponentially reflected in the distance between the coupler and cavity. The evanescent wave approach allows us to predictably reach coupling quality factors of at least in excess of a billion, an extent that may prove a challenge with planar techniques.

Each cavity is measured in a mu-metal magnetic shield within a cryogen-free dilution refrigerator. The shunt resonator technique is adapted for our setup (Fig.1-a), where an SMA-Tee connector is used to introduce the impedance of the cavity under study to our signal path. In this configuration, both coupling and internal quality factors can be obtained without ambiguity of calibration^{5,7,20}. However in the case of very over-coupled measurements, the presence of the coupler may add measurable loss to the cavity mode itself, see asterisked entry in Table I. We design experiments to be nearly critically coupled for maximum signal to noise at low powers. Microwave signals pass through (20 dB and 30 dB) attenuators on the refrigerator's 4 K and 20 mK stages respectively, before entering one port of the SMA-Tee. A second end of the SMA-Tee continues through two Pantech isolators at 20 mK and a cryogenic HEMT at 4 K, followed by room temperature amplification and demodulation. The final Tee-connection is terminated by our coupler and cavity. We analyze the frequency and time domain responses of this circuit at different temperatures and drive powers.

The cavities in our study (Table I) are machined from bulk aluminum with purity ranging from alloy 6061-T6

TABLE I. Representative Results For Aluminum Cavities - (C) Cylindrical, (R) Rectangular, (e) Acid Treated for 4Hrs, (*) Overcoupled with $Q_c=3.7M$

Cavity	Mode	Type	Freq (GHz)	Q_{tot} (10^6)	Q_{int} (10^6)	τ_{int} (ms)
(R1)	TE101	6061	9.513	2.6	5.1	0.08
(R2)	TE101	6061(e)	9.450	1.5	3.2	0.05
(R3)	TE101	4N	9.464	4.3	5.6	0.09
		4N(e)	9.455	30	42	0.7
(R4)	TE101	5N5	9.478	4.2	4.8	0.08
(R5)	TE101 repeat	5N5(e)	9.481	40	43	0.7
		5N5(e)	9.481	61	69	1.2
(C1)	TE111	5N5	7.690	2.4	2.4	0.06
		5N5(e)	7.700	31	31	0.6
		5N5(e)	11.448	14	14	0.2
	TE011	5N5	11.416	56	150	2
		5N5(e)	11.417	280	609	8
(*)		5N5(e)	11.419	3.3	32	0.4
(C2)	TE011 repeat	5N5	11.450	15	15	0.2
		5N5(e)	11.440	340	740	10.4
		5N5(e)	11.442	300	520	7.2

(95%) to 5N5 (99.9995%) pure. Surfaces are treated in a bath of commercially available phosphoric-nitric acid mix, Transene's Aluminum Etchant Type A at 50 °C for 4 Hrs, corresponding to 100 μm of material removed. The acid bath is refreshed upon saturation, about every two hours. Following acid treatment, the cavities are rinsed with high pressure DI water for one minute, rinsed with methanol, and blown dry with nitrogen gas. At this point, the purest aluminum samples are high luster with cm-sized grain boundaries. The cavities then are sealed with indium and stored in room air. No degradation in lifetime has been observed for cavities which remain in such a state for up to six months. We find that switching from alloy to high purity stock is important for aluminum cavities, but also that surface treatment is required to realize that gain. Up to a factor of seventy improvement in cavity lifetime has been observed following this surface treatment. Consistent with reports from niobium resonators^{10,11}, removing 100 μm of material produces the longest lived resonators in bulk aluminum. Etching as much as 220 μm shows no signs of further lifetime gains.

Representative results from several variations of cavity type and preparation measured for this study are shown in Table I. As expected, the TE011 resonance is the longest lived with an intrinsic lifetime of 10.4 ms in one cavity, another nominally identical TE011 resonator reached 8 ms. The longest lived rectangular cavity in this study is 1.2 ms, which is to our knowledge the highest quality rectangular microwave cavity to be reported. We can place lower bounds on the surface dielectric of bulk 5N5 aluminum at $Q_{\text{diel}} \geq 90$ from the rectangular TE101's $Q \times p_{\text{diel}}$ product by assuming $Q = Q_{\text{int,E}}$ and our bulk alu-

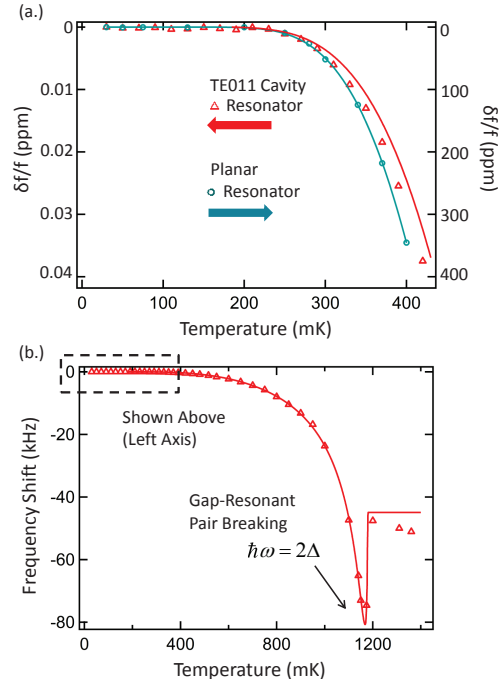


FIG. 2. (Top): Two aluminum resonators (planar and cavity-based) have nearly identical temperature responses, but the cavity resonator's quasiparticle insensitivity is distinguished by its four orders of magnitude smaller frequency shift for equal bath temperatures. (Bottom): Fitting the temperature dependence of a cavity resonator's frequency to the full BCS formalism allows the extraction of a penetration depth, here 65nm, and a critical temperature $T_c=1.18$ K.

minum's quasiparticle surface at $Q_s \geq 4.5k$ from the cylindrical TE011's $Q \times \alpha$ product by assuming $Q = Q_{\text{int,H}}$. These bounds are not a rigid test of aluminum's capabilities. They are comparable to those that would be placed by a coplanar waveguide resonator with $Q \approx 10^4$. This discrepancy highlights the advantage of the macroscopic cavity resonator as a storage resource where material demands are considerably less stringent. Finally, we note that complementary modes (TE111 and TM111) within the cylindrical resonator require $Q_{\text{diel}} \geq 12$ to reach their observed quality factors. Such a modest dielectric layer would allow a TE011 resonance with a 400 ms lifetime. Thus, surface resistive loss or other effects are likely the limiting factors at 10 ms.

Power dependent lifetimes are often observed in planar resonators, with lifetimes falling as much as an order of magnitude from higher powers down to the single photon regime⁶. Dielectric two-level systems (TLS's) concentrated at the surface are a main suspect for this behavior. Given the exceedingly small participation ratios in this study, we do not expect a power dependent response for our cavities. This is confirmed by measurements taken at input powers, P_{in} , such that $\bar{n} = P_{\text{in}}Q/\hbar\omega^2 \approx 1$. For the case of the cylindrical TE011 cavity, no fre-

quency shift between high powers ($P_{\text{in}} = -77$ dBm) and single photon power, here $P_{\text{in}} = -175$ dBm, is observed to ($\delta f/f \leq 4 \times 10^{-10}$), see Fig.1-b. Remarkably, the spectral width of these two data sets, which are separated by nearly 100 dB in drive power, are in complete agreement with $\text{FWHM} = 18 \pm 1$ Hz at low powers. Obtaining a precise spectral width at these low powers required 48 Hrs of averaging. The agreement between high and low powers therefore indicates that the cavity is also frequency stable on these timescales. Further, the lifetimes extracted for these cavities are observed to be independent of whether phase-sensitive heterodyne measurements (Fig.1-b) or phase-insensitive power-decay techniques (Fig.1-c) are used, which suggests $T_2^* \approx 2T_1$ for these devices.

The magnetic participation ratio of a superconducting cavity resonator is directly accessible by observing its frequency response to changing temperatures, an experiment common in the planar resonator community. In fact, the two regimes of superconducting resonators show a striking parallel in their Mattis-Bardeen behavior (Fig.2-a). Note that the planar device, here a lumped-element aluminum resonator on sapphire ($\alpha = 0.07$), experiences the effect of the equilibrium quasiparticles much more than the cavity resonator does ($\delta f/f \propto \alpha$). Equilibrium quasiparticle sensitivity extends to the nonequilibrium limits as well. Thus, one would expect a many orders of magnitude longer lifetime for the nonequilibrium quasiparticle-limited cavity resonator. Because the field components of (Eq.2) are analytically calculable for cavities, this experiment is equivalent to the extraction of the penetration depth. A numerical integration of aluminum's full BCS conductivity allows for fitting our cavities' frequency response across their critical temperature (Fig.2-b). In particular, the sharp drop in frequency (corresponding to a spike in surface reactance) near $T_c = 1.18$ K is indicative of pair-breaking due to circulating photon energies equal to the superconducting energy gap. The location of this drop, as well as the plateau in frequency above T_c allows a precise extraction of our aluminum sample's penetration depth, 65 ± 2 nm. With etching, we find a decrease in penetration depth to 52 ± 2 nm, indicating a cleaner superconducting state has been formed. We believe that that lifetime gains accompanying surface treatment are related to this effect.

Residual magnetic field is a suspect for limiting the cavity lifetimes in this study to the order of 10ms. Although thermally cycling devices through T_c has no observable effect during an experimental run ($\delta\omega \ll 1/\kappa$), significant changes to the magnetic environment between runs such as changing the isolator configuration or switching to less permeable microwave lines have been seen to affect lifetimes by a factor two. Outside of a magnetic shield, the superconducting aluminum cavity resonators are unstable, jumping several linewidths at base temperatures in response to magnetic perturbations outside the dilution refrigerator.

In conclusion, we have measured multiple aluminum

cavity resonators capable of storing single microwave photons for 1-10 ms at millikelvin temperatures. This is the first step in realizing the potential leap in coherence promised by nonplanar resources in cQED experiments.

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